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Hyperfast Rectifier, 15 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)}	15 A					
V _R	1200 V					
V _F at I _F at 125 °C	1.7 V					
t _{rr}	37 ns					
T _J max.	175 °C					
Package	TO-220AC 2L					
Circuit configuration	Single					

FEATURES

- Hyperfast and optimized Q_{rr}
- Best in class forward voltage drop and switching RoHS
 losses trade off
 HALOGEN
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-220AC 2L

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

Polarity: as per marking device details

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Repetitive peak reverse voltage	V _{RRM}		1200	V				
Average rectified forward current	I _{F(AV)}	T _C = 110 °C, D = 0.50	15					
Repetitive peak forward current	I _{FRM}	T _C = 110 °C, D = 0.50, f = 20 kHz	30	А				
Non-repetitive peak surge current	I _{FSM}	$T_C = 45 \text{ °C}, t_p = 10 \text{ ms}, \text{ sine wave}$	125					
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	1200	-	-			
Forward voltage	V _F	I _F = 15 A	-	1.9	2.5	V		
Forward voltage		I _F = 15 A, T _J = 125 °C	-	1.7	-			
Deverse leakerse eurrent	I _R	$V_{R} = V_{R}$ rated	-	-	50			
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500 µA			
Junction capacitance	CT	V _R = 200 V	-	10	-	pF		
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH		

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
		I _F = 1.0 A, dI _F /dt =	100 A/ μ s, V _R = 30 V	-	37	50			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	95	-	ns		
		T _J = 125 °C		-	146	-			
Peak recovery current		T _J = 25 °C	I _F = 10 A dI _F /dt = 600 A/μs V _R = 400 V	-	14	-	A		
Feak recovery current	I _{RRM}	T _J = 125 °C		-	19	-			
Poverse receivery charge	0	T _J = 25 °C		-	545	-	nC		
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1200	-			
Reverse recovery time	+	T _J = 25 °C		-	75.5	-	ns		
Reverse recovery time	t _{rr}	T _J = 125 °C		-	100	-	115		
Deale recovery everyeast		T _J = 25 °C	$I_{\rm F} = 15 {\rm A}$	-	23	-	А		
Peak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 1000 A/µs V _B = 800 V	-	35	-			
	0	T _J = 25 °C		-	935	-			
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1985	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.7	°C/W			
Weight			-	2.0	-	g			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C			
Marking device		Case style TO-220AC 2L	E5TH1512						

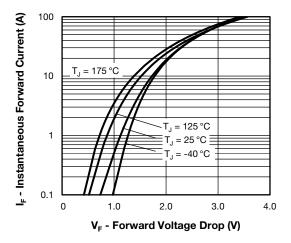


Fig. 1 - Forward Voltage Drop Characteristics

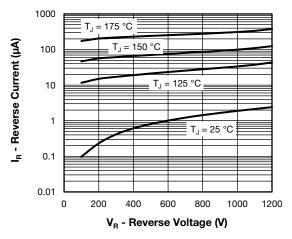


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



VS-E5TH1512-M3

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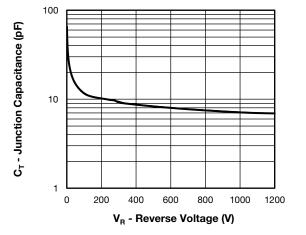


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

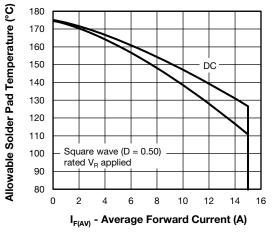


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

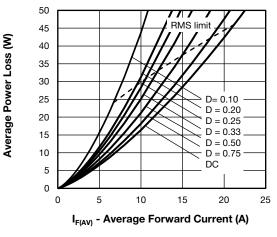


Fig. 5 - Forward Power Loss Characteristics

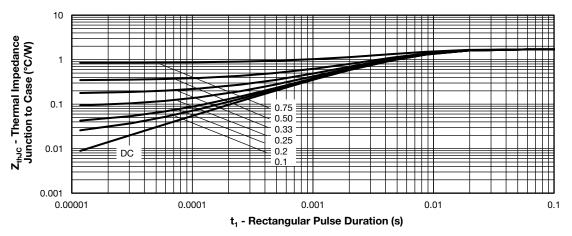


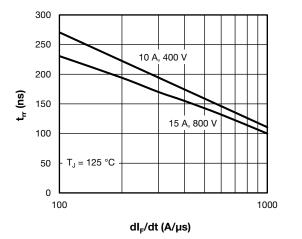
Fig. 6 - Transient Thermal Impedance, Junction to Case

Revision: 16-May-2022

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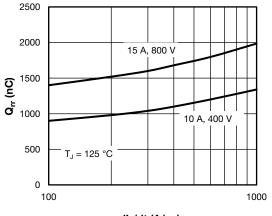




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Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt



 dI_F/dt (A/µs) Fig. 8 - Typical Stored Charge vs. dI_F/dt

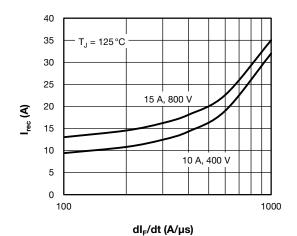


Fig. 9 - Typical Stored Charge vs. dl_F/dt





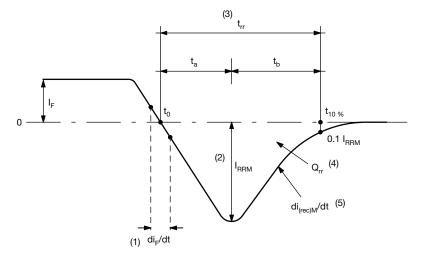


Fig. 10 - Reverse Recovery Waveform and Definitions

Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}\,$ Qrr area under curve defined by t_0 and t_{10} $_{\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t) dt$$

 $^{(5)}$ di_{(rec)}M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

Device code	VS-	E	5	т	н	15	12	-МЗ
		2	3	4	5	6	7	8
	1 ·	- Visł	nay Sem	nicondu	ctors pr	oduct		
	2 ·	E=	single o	diode				
	3 -	- 5 =	FRED g	jeneratio	on 5			
	4 -	· Pac	kage:					
		-	TO-220					
	5 -	• H=	hyperfa	ast reco	very			
	6	- Cur	rent rati	ng (15 =	= 15 A)			
	7	- Vol	tage rati	ing (12 =	= 1200 \	/)		
	8 -	- Env	rironmer	ntal digit	:			
		-M3	3 = halo	gen-free	e, RoHS	-compli	ant, and	d termin

ORDERING INFORMATION (Example)					
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-E5TH1512-M3	50	Antistatic plastic tubes			
VS-E3TH1512-W3	50	Antistatic plastic tubes			

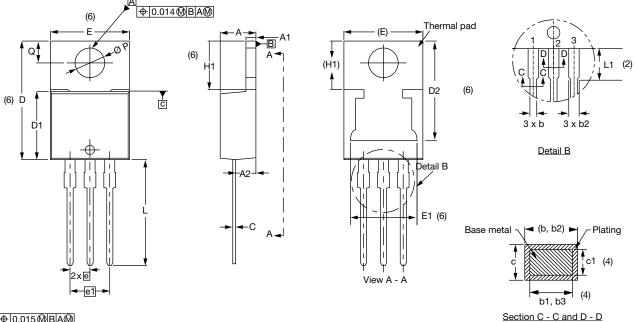
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TO-220AB 3L

DIMENSIONS in millimeters and inches



⊕0.015@BA@



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SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

SYMBOL		IEIERƏ	INCHES		NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØP	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

INCHES

Notes

⁽²⁾ Lead dimension and finish uncontrolled in L1

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

⁽⁵⁾ Controlling dimensions: inches

- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- ⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

Revision: 14-Mar-2022

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Conforms to JEDEC[®] outline TO-220AB

MILLIMETEDS

 $^{^{(1)}\,}$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body



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